

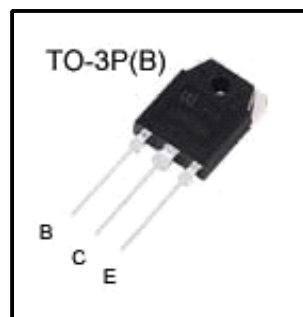
High voltage Fast Switching NPN Power Transistor

Features

- Very High Switching Speed
- High voltage Capability
- Wide Reverse Bias SOA

General Description

This Device is designed for high voltage, High speed switching characteristics required such as lighting system, switching mode power supply.



Absolute Maximum Ratings

Symbol	Parameter	Test Conditions	Value	Units
V_{CES}	Collector -Emitter Voltage	$V_{BE}=0$	700	V
V_{CEO}	Collector -Emitter Voltage	$I_B=0$	400	V
V_{EBO}	Emitter -Base Voltage	$I_C=0$	9.0	V
I_C	Collector Current		12	A
I_{CP}	Collector pulse Current		25	A
I_B	Base Current		6.0	A
I_{BM}	Base Peak Current	$t_p=5ms$	12	A
P_C	Total Dissipation at $T_c=25^{\circ}C$		110	W
T_J	Operation Junction Temperature		-40~150	$^{\circ}C$
T_{STG}	Storage Temperature		-40~150	$^{\circ}C$

Thermal Characteristics

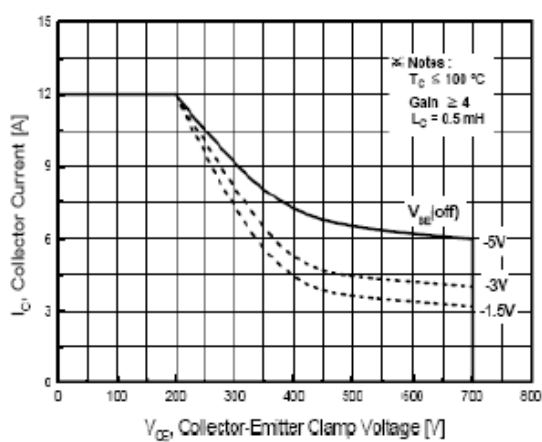
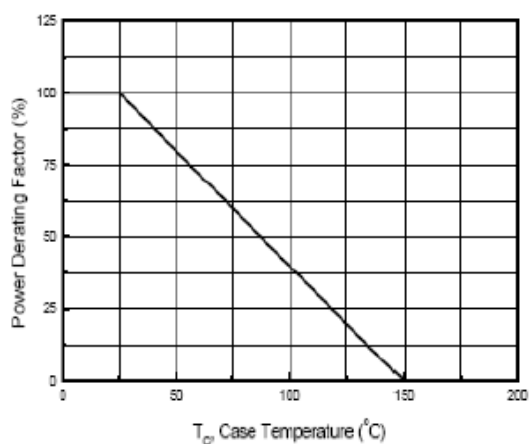
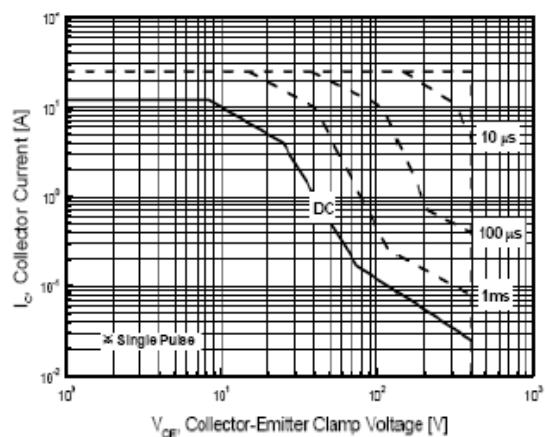
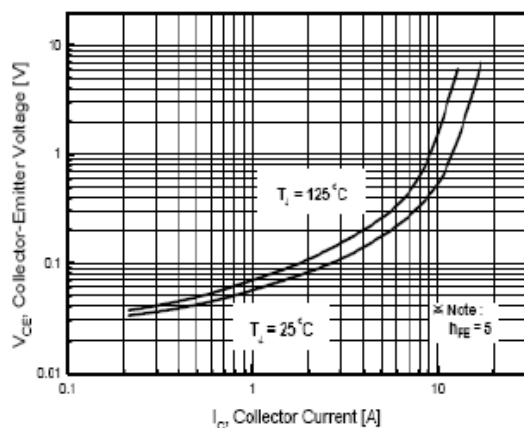
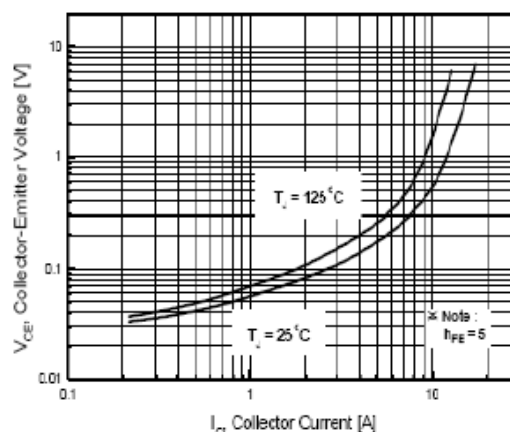
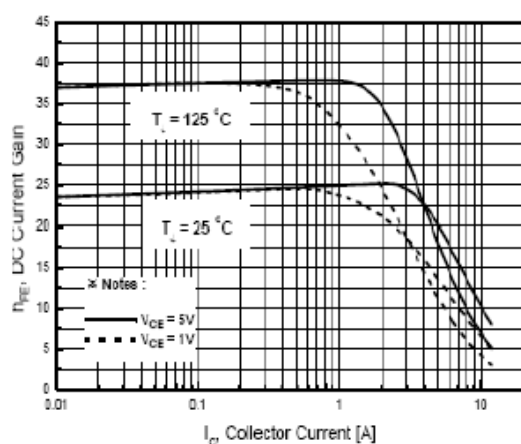
Symbol	Parameter	Value	Units
$R_{\theta JC}$	Thermal Resistance Junction to Case	1.13	$^{\circ}C/W$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient	62.5	$^{\circ}C/W$

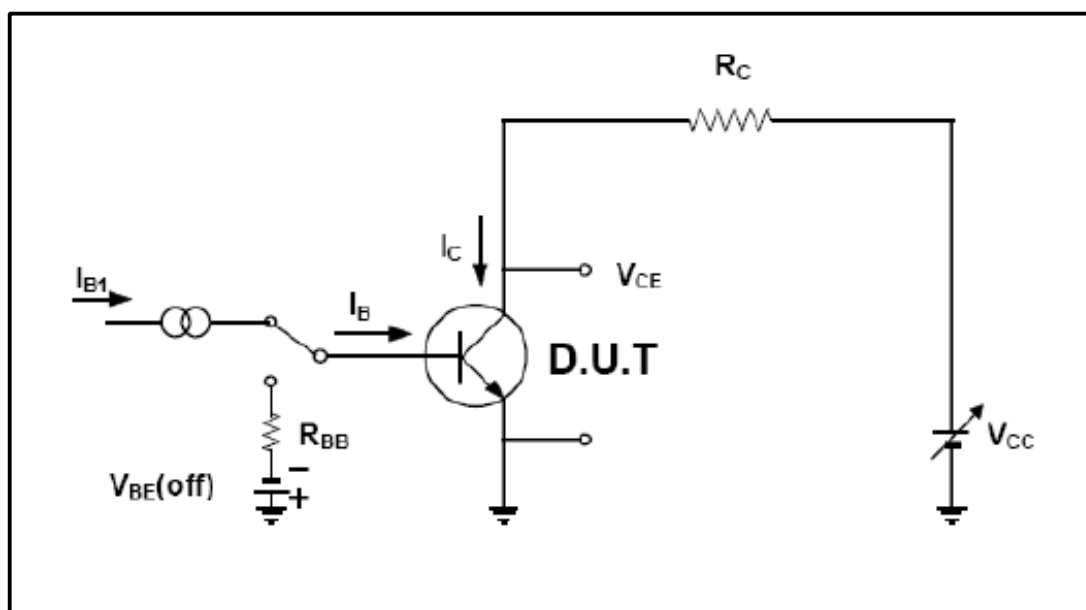
Electrical Characteristics

Symbol	Parameter	Test conditions	Value			Units
			Min	Typ	Max	
$V_{CEO(sus)}$	Collector-Emitter Breakdown Voltage	$I_c=10mA, I_b=0$	400	-	-	V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_c=5.0A, I_b=1.0A$			1.0	V
		$I_c=8.0A, I_b=1.6A$	-	-	1.5	
		$I_c=12A, I_b=3.0A$			3.0	
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_c=8.0A, I_b=1.6A$ $T_c=100^{\circ}C$	-	-	2.0	V
		$I_c=5.0A, I_b=1.0A$ $I_c=8.0A, I_b=1.6A$	-	-	1.2 1.6	V
		$I_c=8.0A, I_b=1.6A$ $T_c=100^{\circ}C$	-	-	1.5	V
I_{EBO}	Emitter -Base Cutoff Current	$V_{eb}=9V, I_c=0V$	-	-	10	μA
hFE	DC Current Gain	$V_{ce}=5V, I_c=5.0A$	10	-	40	
		$V_{ce}=5V, I_c=8.0A$	6	-	30	
t_s	Storage Time	$V_{cc}=5.0V, I_c=0.5A$ (UI9600)	4	-	10	μs
t_f	Fall Time			-	0.8	
f_T	Current Gain Band width Product	$V_{ce}=10V, I_c=0.5A$	4			MHz

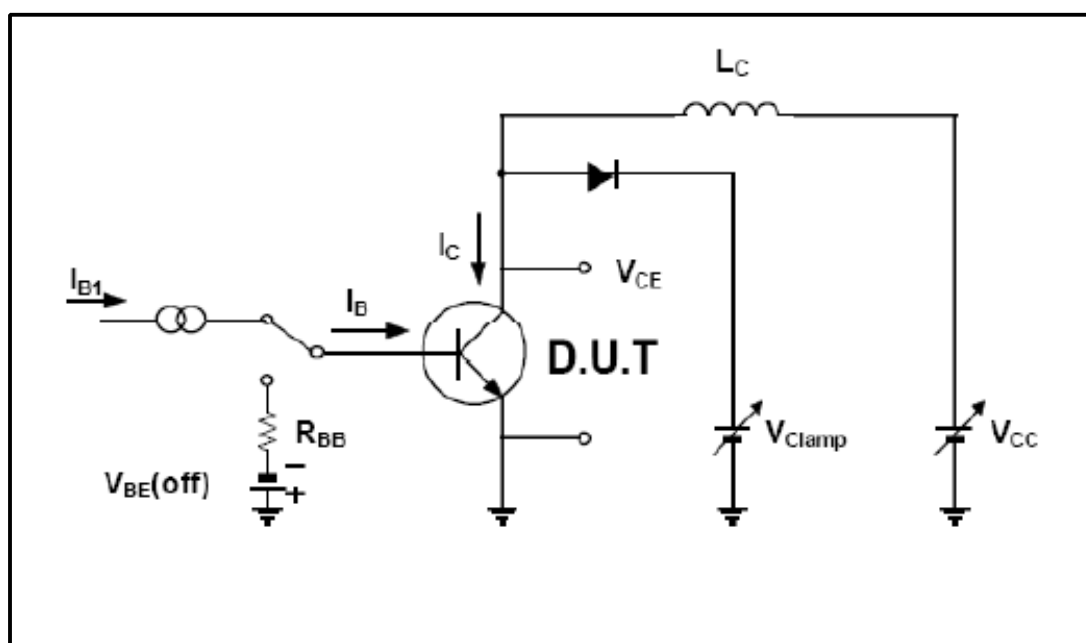
Note :

Pulse Test :Pulse width 300,Duty cycle 2%





Resistive Load Switching Test Circuit



Inductive Load Switching & RBSOA Test Circuit

TO3P(B)Package Dimension

Unit :mm

